NSN 5961-01-037-8876

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-037-8876 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.700 inches **Overall Width:** 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open and 50.0 collector-to-emitter, with voltage between base and emitter **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 29.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig:

No

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